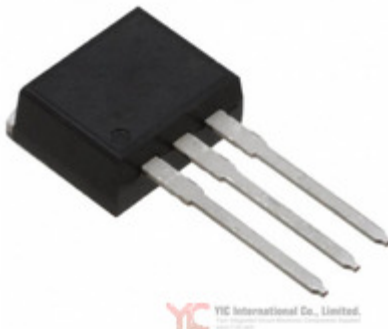



	<h2 style="color: red;">FQI27N25TU</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQI27N25TU
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 250V 25.5A I2PAK
	Datenblätter:  FQI27N25TU.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 1000 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQI27N25TU
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 250V 25.5A I2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1000 pcs Stock
detaillierte Beschreibung	N-Channel 250V 25.5A (Tc) 3.13W (Ta), 180W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-262-3 Long Leads, I ² Pak, TO-262AA
Supplier Device-Gehäuse	I2PAK (TO-262)
Verlustleistung (max)	3.13W (Ta), 180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	25.5A (Tc)
Rds On (Max) @ Id, Vgs	110 mOhm @ 12.75A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	65nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2450pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)



















































FQI27N25TU ist neu im Original, Suche FQI27N25TU Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQI27N25TU AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQI27N25TU: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQI1P50TU Fairchild/ON Semiconductor MOSFET P-CH 500V 1.5A I2PAK</p>	 <p>FQI1P50TU AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 1.5A I2PAK</p>	 <p>FQI19N20CTU AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A I2PAK</p>	 <p>FQI27N25TU_F085 Fairchild/ON Semiconductor MOSFET N-CH 250V 25.5A I2PAK</p>
 <p>FQI27P06 FAIRCHILD FQI27P06 FAIRCHILD</p>	 <p>FQI27N25TU Fairchild/ON Semiconductor MOSFET N-CH 250V 25.5A I2PAK</p>	 <p>FQI27P06TU Fairchild/ON Semiconductor MOSFET P-CH 60V 27A I2PAK</p>	 <p>FQI27N25TU-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A I2PAK</p>

heiße Teile

Mehr

 FQI10N20CTU	 FQI10N20CTU	 FQI10N20LTU	 FQI11P06TU	 FQI11P06TU
 FQI12N60C	 FQI13N06	 FQI13N06L	 FQI13N50	 FQI13N50C
 FQI13N50CTU	 FQI13N50CTU	 FQI16N15TU	 FQI17N08L	 FQI17P06TU
 FQI17P06TU	 FQI17P20	 FQI19N10LTU	 FQI19N20TU	 FQI19N20TU
 FQI27N25TU	 FQI2N50TU	 FQI2NA90	 FQI2P25TU	 FQI2P25TU
 FQI3N25TU	 FQI3N25TU	 FQI3N30TU	 FQI3N30TU	 FQI47P06TU
 FQI47P06TU	 FQI4N20TU	 FQI4N20TU	 FQI4N80TU	 FQI4N80TU
 FQI4N90TU	 FQI4N90TU	 FQI50N06	 FQI50N06L	 FQI5N20L
 FQI5N50CTU	 FQI5N50CTU	 FQI5N50TU	 FQI5N60C	 FQI5N60CTU
 FQI5N60CTU	 FQI5N60TU	 FQI6N25TU	 FQI6N40TU	 FQI6N60C

Contact us: Info@Y-IC.com

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